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NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 100 mA.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Thermal Characteristics TA = 25°C unless otherwise noted			
Symbol	Characteristic	Мах	Units
		2N4123	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
R _{0.IA}	Thermal Resistance, Junction to Ambient	200	°C/W

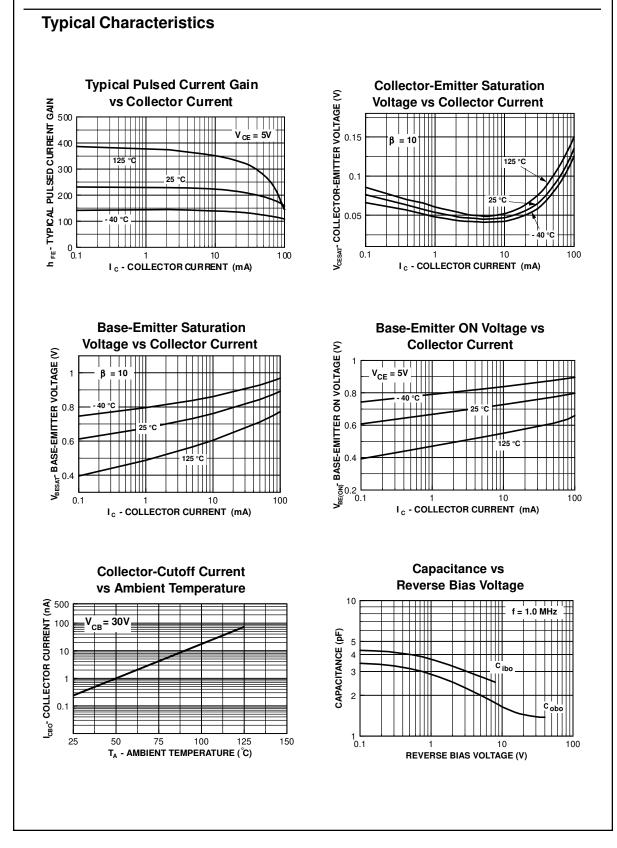
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NPN General Purpose Amplif

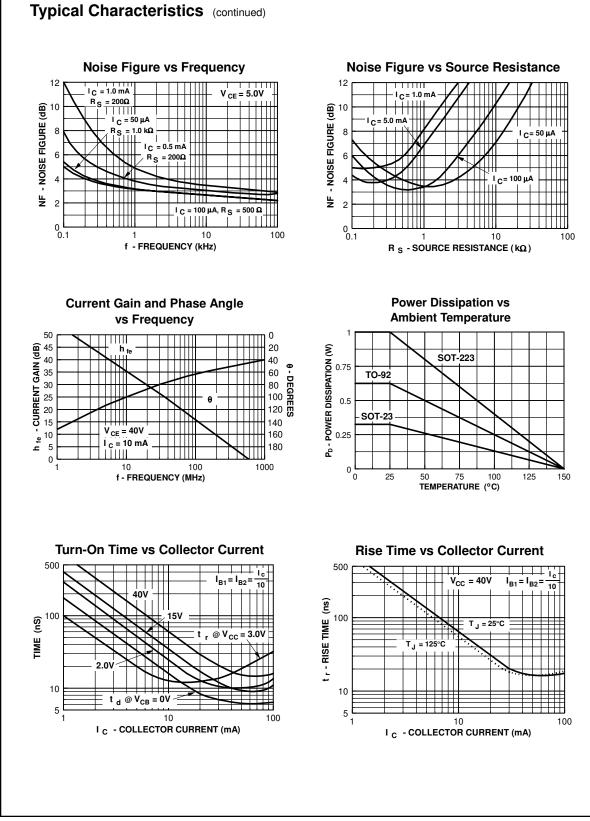
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Symbol	Parameter	Test Conditions	Min	Мах	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	30		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	40		V
V _{(BR)EBO} Emitter-Base Breakdown Voltage		$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	5.0		V
СВО	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_{E} = 0$		50	nA
EBO	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
/ _{CE(sat)}	Collector-Emitter Saturation Voltage	$V_{CE} = 1.0 \text{ V}, \text{ I}_{C} = 50 \text{ mA}$ I _C = 50 mA, I _B = 5.0 mA	25	0.3	V
	Collector Emitter Saturation Voltage		25	0.2	V
	Base-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA	-	0.3	V V
V _{BE(sat)}	Base-Emilier Saturation voltage	$T_{C} = 50 \text{ IIIA}, T_{B} = 5.0 \text{ IIIA}$		0.95	v
SMALL S	IGNAL CHARACTERISTICS				
C _{ob}	Output Capacitance	$V_{CB} = 5.0 \text{ V}, \text{ f} = 100 \text{ kHz}$		4.0	pF
Cib	Input Capacitance	$V_{EB} = 0.5 V, f = 0.1 MHz$		8.0	pF
Ĵfe	Small-Signal Current Gain	$I_{\rm C} = 2.0 \text{ mA}, V_{\rm CE} = 10 \text{ V},$	= 0		
		f = 1.0 kHz I _C = 10 mA, V _{CE} = 20 V,	50	200	
		f = 100 MHz	2.5		
Т	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V}$ f = 100 MHz	250		MHz
NF	Noise Figure	$V_{CE} = 5.0 \text{ V}, I_{C} = 100 \ \mu\text{A},$		6.0	dB
		$R_{s} = 1.0 k\Omega$,			
		B _w = 10 Hz to 15.7 kHz			

NPN General Purpose Amplifier (continued)

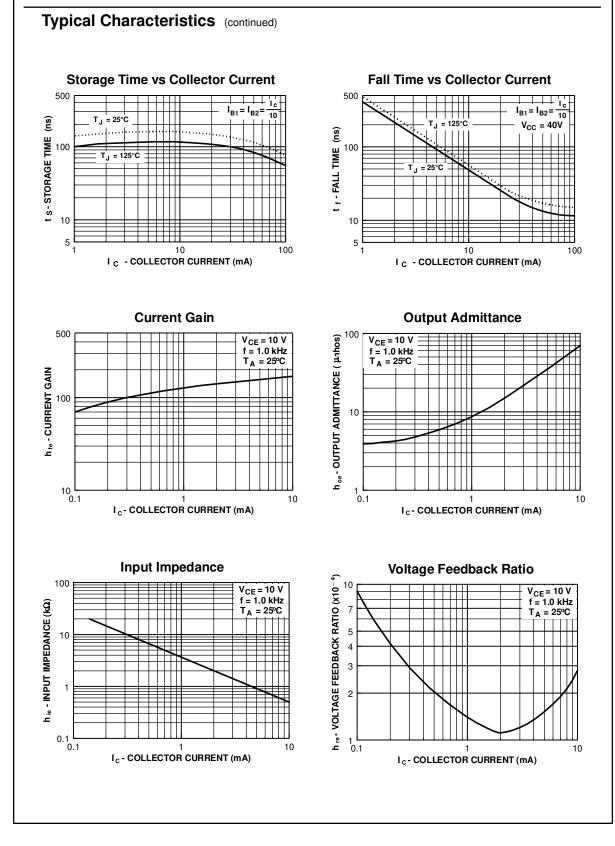


NPN General Purpose Amplifier (continued)





NPN General Purpose Amplifier (continued)





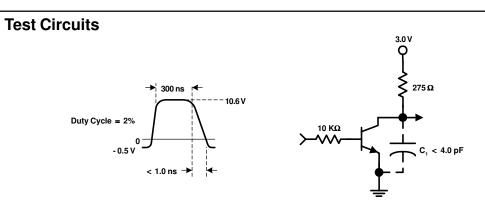


FIGURE 1: Delay and Rise Time Equivalent Test Circuit

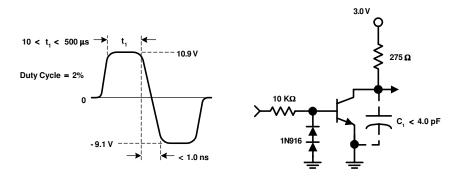


FIGURE 2: Storage and Fall Time Equivalent Test Circuit

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